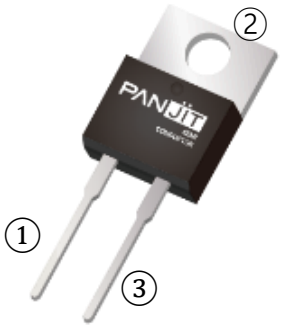
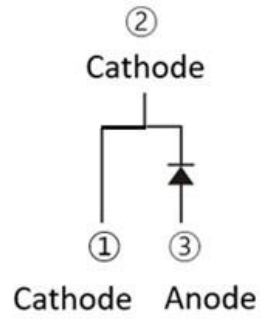
Silicon Carbide Schottky Barrier Diode

V_{RRM}	650 V	I_F	8 A
$V_{F(Typ.)}$	1.3 V	Q_C	25 nC

TO-220AC





Features

- Positive Temperature Coefficient on V_F
- Low Conduction Loss
- Zero Reverse Recovery
- High junction temperature 175 °C
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case: TO-220AC molded plastic
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 1.8903 grams

Application

- PFC, UPS, PV Inverter

Maximum Ratings and Thermal Characteristics (T_C = 25 °C unless otherwise specified)

PARAMETER		SYMBOL	LIMIT	UNITS
Repetitive Peak Reverse Voltage		V_{RRM}	650	V
DC Blocking Voltage		V_{DC}	650	V
Continuous Forward Current	T_C= 156 °C	I_F	8	A
Repetitive Peak Surge Current	T_C= 25 °C , t_p =10ms	I_{FRM}	52	A
Half Sine Wave, D=0.1	T_C=125 °C , t_p =10ms		44	
Peak Forward Surge Current	T_C= 25 °C , t_p =10ms	I_{FSM}	60	A
Half Sine Wave	T_C=125 °C , t_p =10ms		48	
Peak Forward Surge Current	*t_p =10us, Pulse*		680	A
i^2t value	T_C= 25 °C , t_p =10ms	$\int i^2dt$	19	A^2s
	T_C=125 °C , t_p =10ms		15.2	
Maximum Power Dissipation		P_{total}	96.2	W
Operating Junction Temperature Range		T_J	-55~175	°C
Storage Temperature Range		T_{STG}	-55~175	°C

Electrical Characteristics (T_C = 25 °C unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Forward Voltage Drop	V_F	I_F = 8 A, T_J = 25 °C	-	1.3	1.55	V
		I_F = 8 A, T_J = 125 °C	-	1.43	-	
		I_F = 8 A, T_J = 175 °C	-	1.55	-	
Reverse Leakage Current	I_R	V_R = 650 V, T_J = 25 °C	-	0.04	20	μA
		V_R = 650 V, T_J = 175 °C	-	1.2	-	μA
Total Capacitive Charge	Q_C	I_F = 8A, V_R = 400V	-	25	-	nC
Total Capacitance	C	V_R = 1V, f = 1MHz	-	415	-	pF
		V_R = 200V, f = 1MHz	-	50	-	pF
		V_R = 400V, f = 1MHz	-	38	-	pF
Capacitance Stored Energy	E_C	V_R = 400V	-	4	-	μJ
Thermal Resistance	$R_{\theta JC}$		-	1.2	1.56	°C/W

TYPICAL CHARACTERISTIC CURVES

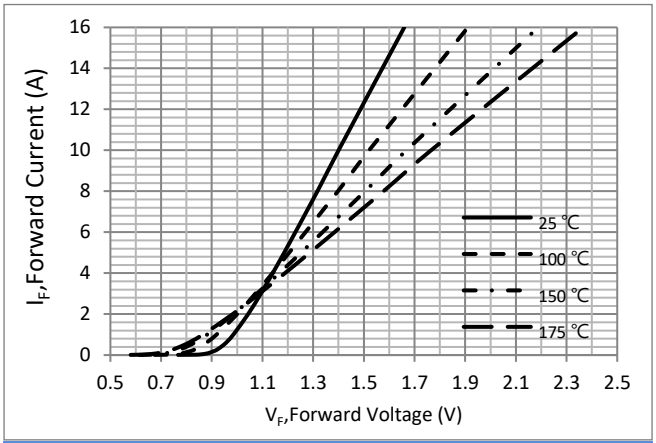


Fig.1 Forward Characteristics

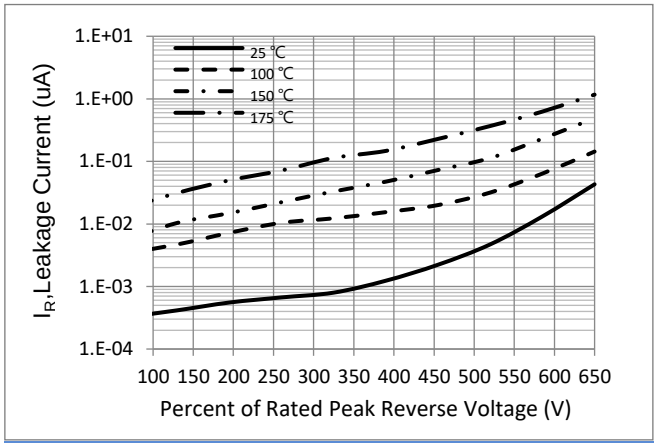


Fig.2 Reverse Characteristics

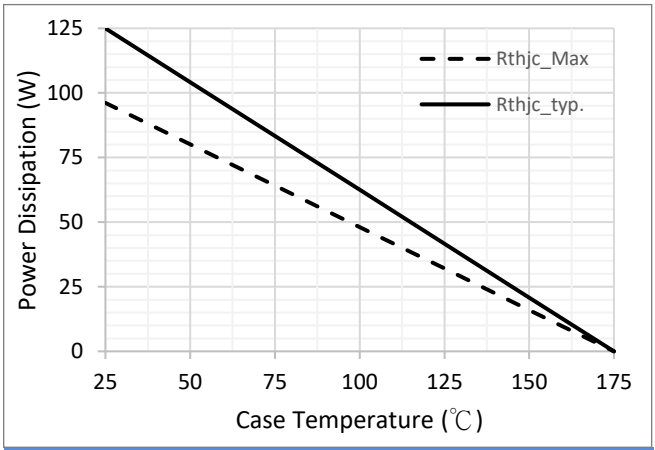


Fig.3 Power Derating Curve

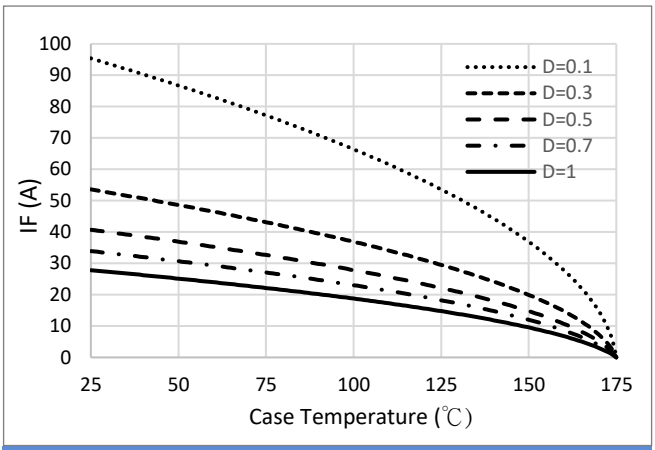


Fig.4 Maximum Forward Current

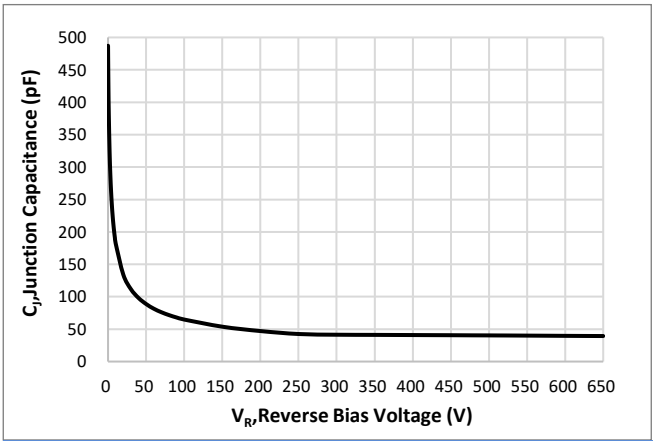


Fig.5 Typical Junction Capacitance

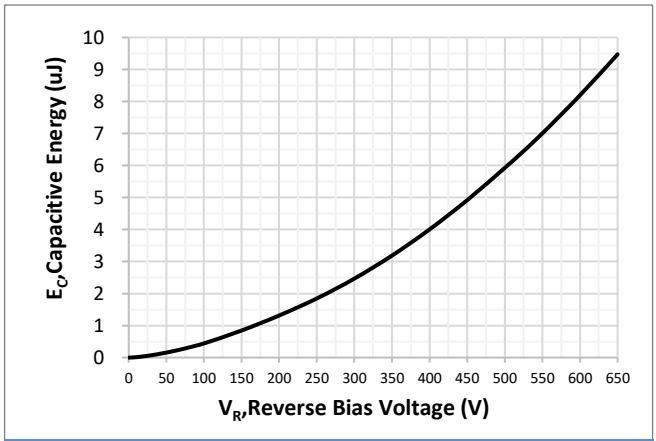


Fig.6 Capacitance Stored Energy

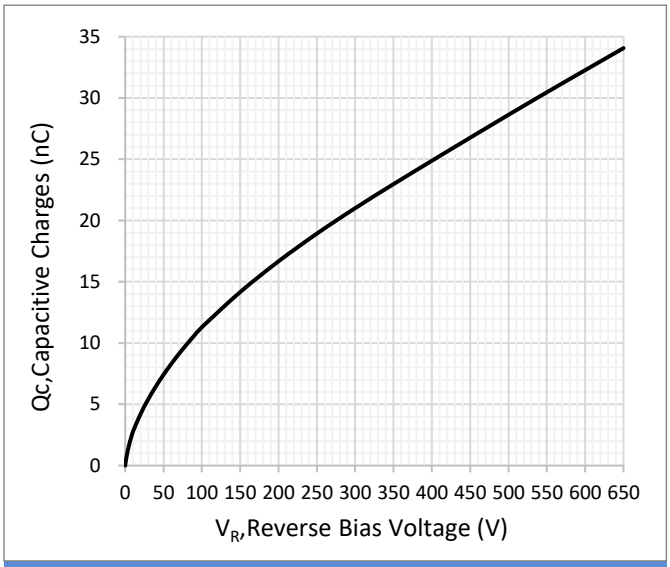


Fig.7 Total capacitive charges VS. Reverse voltage applied (typical values)

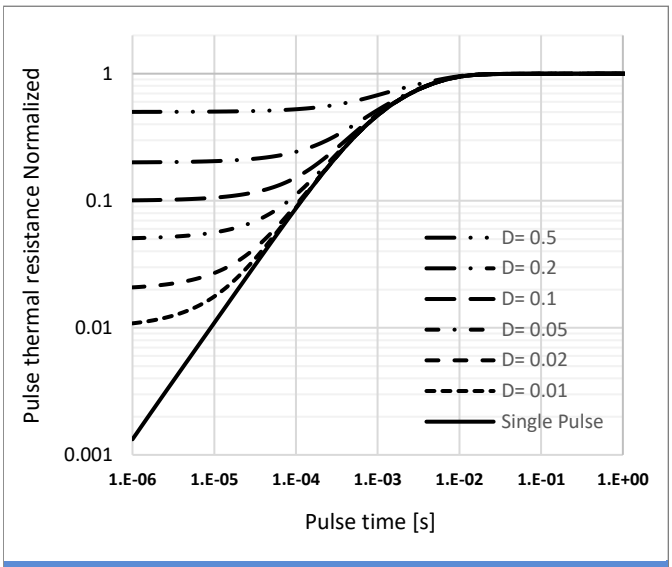


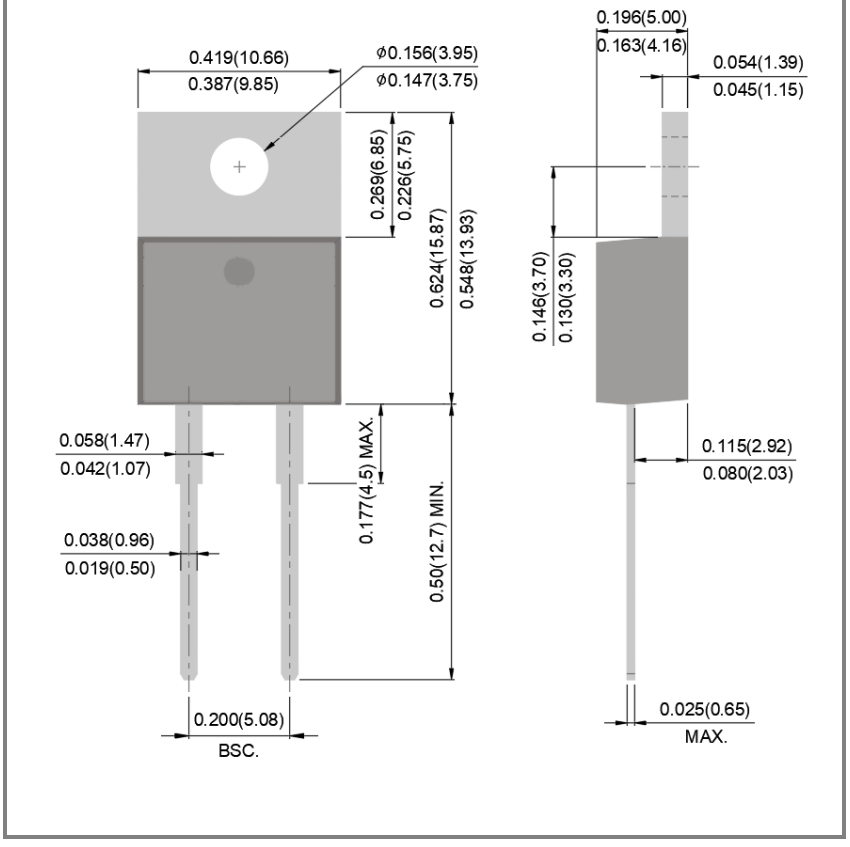
Fig.8 Max. Transient thermal impedance

Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PCDP0865G3	TO-220AC	50pcs / Tube	CDP0865G3

Packaging Information

TO-220AC Dimension — Unit: inch(mm)



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